

STA3350L

PNP Silicon Transistor

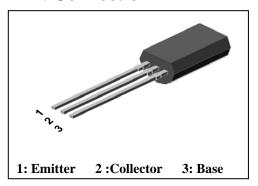
Applications

- Power amplifier application
- High current switching application

Features

- Low saturation voltage: $V_{\text{CE(sat)}}$ =-0.15V Typ. @ I_{C} =-1A, I_{B} =-50mA
- \bullet Large collector current capacity: $I_C = -3A$

PIN Connection



Ordering Information

Type NO.	Marking	Package Code
STA3350L	STA3350	TO-92L

Absolute Maximum Ratings

[Ta=25°C]

Thospitate Waximum Ratings			
Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-50	V
Collector-emitter voltage	$V_{\sf CEO}$	-50	V
Emitter-base voltage	V_{EBO}	-6	V
Callagton gumant	${ m I}_{\sf C}$	-3	A(DC)
Collector current	${ m I}_{\sf CP}*$	-6	A(Pulse)
Collector Power dissipation(Ta=25°C)	P _C	1	W
Junction temperature	T ₃	150	°C
Storage temperature range	T_{stg}	-55~150	°C

^{*:} Single pulse, tp= 300 μ s

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STA3350L

Electrical Characteristics

[Ta=25℃]

Charac	teristic	Symbol	ymbol Test Condition		Тур.	Max.	Unit
Collector-emitter b	lector-emitter breakdown voltage BV_{CEO} I_{C} =-1mA, I_{B} =0		-50	-	-	V	
Collector cut-off current		I_{CBO}	V _{CB} =-50V, I _E =0	-	-	-1	μΑ
Emitter cut-off current		I_{EBO}	V _{EB} =-6V, I _C =0	-	-	-1	μΑ
DC current gain		h _{FE}	V _{CE} =-2V, I _C =-0.5A*	120	-	240	
		h _{FE}	V _{CE} =-2V, I _C =-2A*	40	-	1	
Collector-emitter saturation voltage		$V_{CE(sat)}$	I _C =-1A, I _B =-0.05A*	-	-	-0.35	V
Base-emitter saturation voltage		$V_{BE(sat)}$	I _C =-2A, I _B =-0.1A*	-	-0.97	-1.2	V
Transition frequenc	су	f_{T}	V _{CE} =-10V, I _C =-0.05A	-	250	-	MHz
Collector output capacitance		C _{ob}	V _{CB} =-10V, I _E =0, f=1MHz	-	28	-	pF
Switching Time	Turn-on Time	t _{on}	IBI I INPUT IBE OUTPUT	-	100	-	
	Storage Time	t _{stg}	2015	-	300	-	ns
	Fall Time	t _f	-ibi=ib≥=100mA DUTY dycle ≤1%	1	50	-	

^{*:} Pulse test : $t_P \le 300 \mu s$, Duty cycle $\le 2\%$

Electrical Characteristic Curves

Fig. 1 P_C - T_a

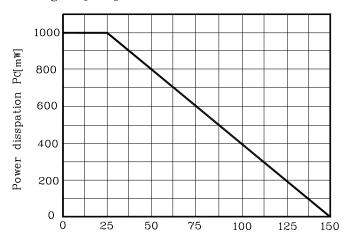


Fig. 2 I_C - V_{BE}

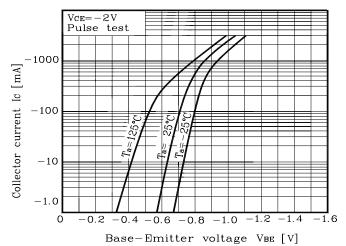


Fig. 3 I_C - V_{CE}

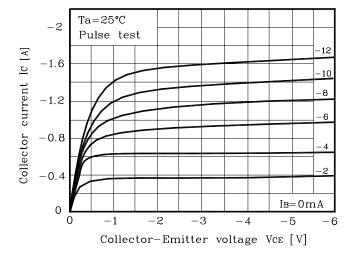


Fig. 4 h_{FE} - I_C

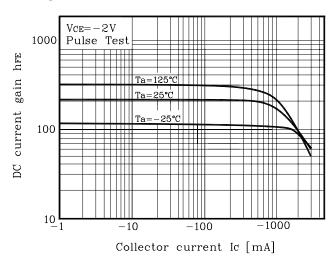


Fig. 5 $V_{\text{CE}(\text{sat})}$ - I_{C}

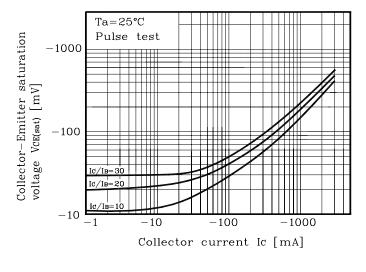
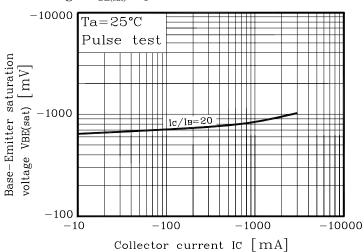


Fig. 6 $V_{BE(sat)}$ - I_{C}



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Electrical Characteristic Curves

Fig. 7 C_{Ob} - V_{CB}

1000

Indian of 1000

Ta=25°C

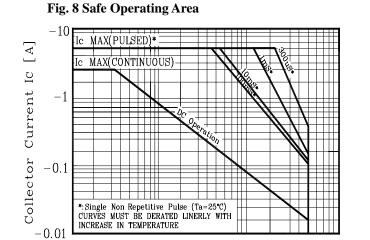
Ta=25°C

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Collector-base voltage Vcb [V]



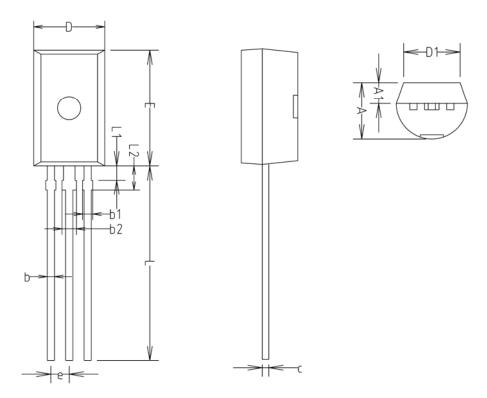
-1.0

-0.1

-10

-100

Outline Dimension



CHARDOL	MILLMETERS(mm)			NOTE
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	NOTE
Α	3.70	3.90	4.10	
A1	1.25	1.45	1.65	
b	0.40	0.50	0.60	
b1	_	_	0.70	
b2	_	_	1.00	
С	0.35	0.45	0.55	
D	4.70	4.90	5.10	
D1	3.70	3.90	4.10	
Ε	7.80	8.00	8.20	
е	1.27 TYP			
L	13.10	13.50	13.90	
L1	0.90	1.00	1.10	
L2	1.50	1.70	1.90	

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